

Medium Power Transistor (25V, 1.2A)

2SD2537

●Features

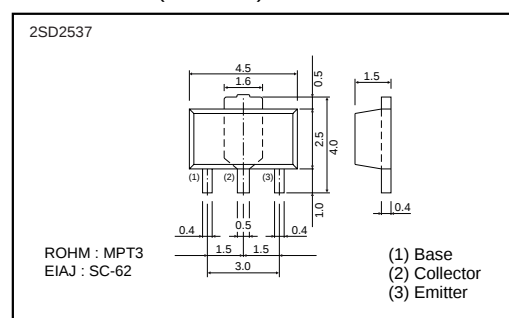
- 1) High DC current gain.
- 2) High emitter-base voltage. ($V_{EB0}=12V$)
- 3) Low saturation voltage.
(Max. $V_{CE(sat)}=0.3V$ at $I_C/I_B=500mA/10mA$)

●Absolute maximum ratings ($T_a=25^{\circ}C$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CB0}	30	V
Collector-emitter voltage	V_{CE0}	25	V
Emitter-base voltage	V_{EB0}	12	V
Collector current	I_C	1.2	A (DC)
		2	A (Pulse) *1
Collector power dissipation	P_C	0.5	W
		2	W *2
Junction temperature	T_J	150	$^{\circ}C$
Storage temperature	T_{stg}	-55 to +150	$^{\circ}C$

*1 Single pulse $P_w=100ms$ *2 When mounted on a $40 \times 40 \times 0.7mm$ ceramic board.

●Dimensions (Unit : mm)



●Packaging specifications and h_{FE}

Type	2SD2537
Package	MPT3
h_{FE}	V
Marking	DV
Code	T100
Basic ordering unit (pieces)	1000

●Electrical characteristics ($T_a=25^{\circ}C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CB0}	30	—	—	V	$I_C=10\mu A$
Collector-emitter breakdown voltage	BV_{CE0}	25	—	—	V	$I_C=1mA$
Emitter-base breakdown voltage	BV_{EB0}	12	—	—	V	$I_E=10\mu A$
Collector cutoff current	I_{CBO}	—	—	0.3	μA	$V_{CB}=30V$
Emitter cutoff current	I_{EBO}	—	—	0.3	μA	$V_{EB}=12V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.3	V	$I_C/I_B=500mA/10mA$ *
Base-emitter saturation voltage	$V_{BE(sat)}$	—	—	1.2	V	$I_C/I_B=0.5A/10mA$
DC current transfer ratio	h_{FE}	820	—	1800	—	$V_{CE}/I_C=5V/0.5A$
Transition frequency	f_T	—	200	—	MHz	$V_{CE}=10V, I_E=-50mA, f=100MHz$ *
Output capacitance	C_{ob}	—	20	—	pF	$V_{CB}=10V, I_E=0A, f=1MHz$

*Measured using pulse current.

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●Electrical characteristics curves

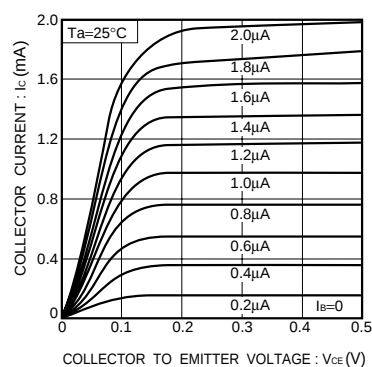


Fig.1 Ground emitter output characteristics (I)

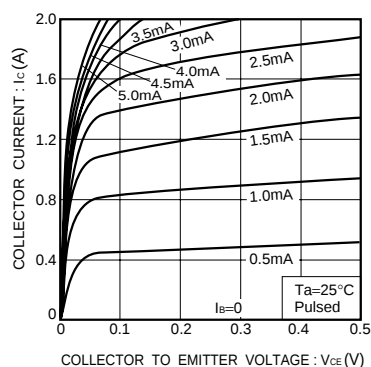


Fig.2 Ground emitter output characteristics (II)

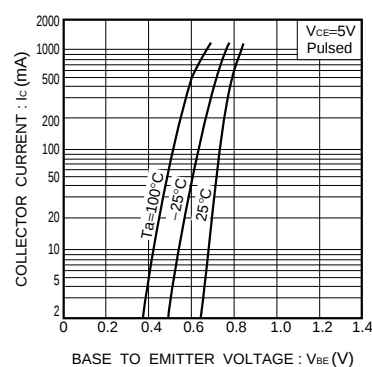


Fig.3 Ground emitter propagation characteristics

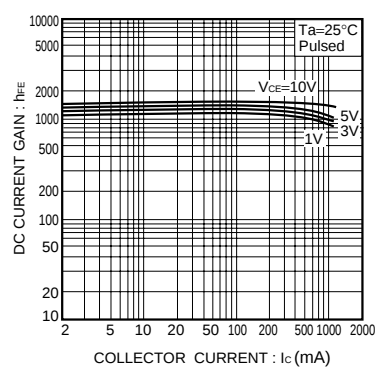


Fig.4 DC current gain vs. collector current (I)

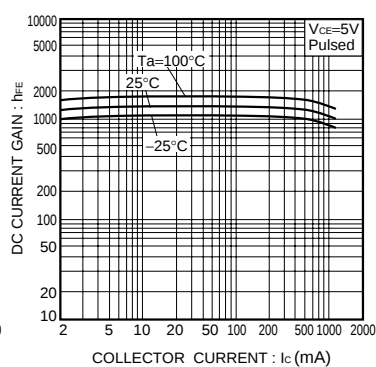


Fig.5 DC current gain vs. collector current (II)

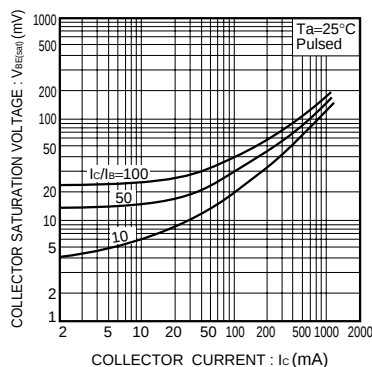


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

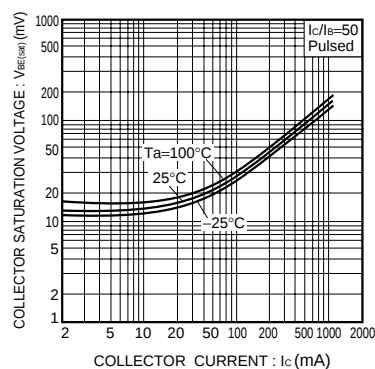


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

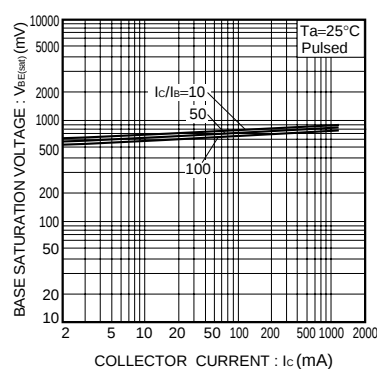


Fig.8 Base-emitter saturation voltage vs. collector current (I)

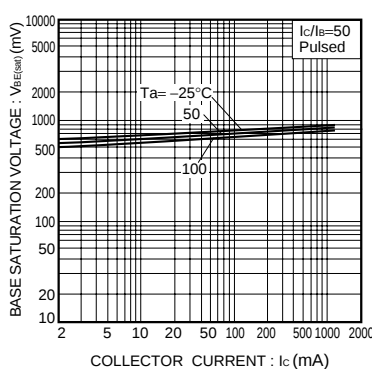


Fig.9 Base-emitter saturation voltage vs. collector current (II)

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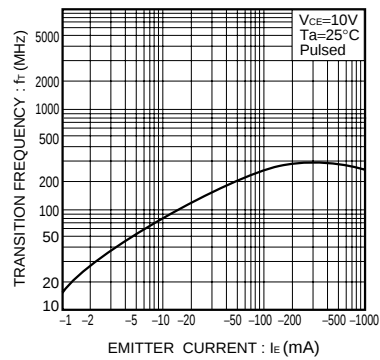


Fig.10 Gain bandwidth product
vs. emitter current

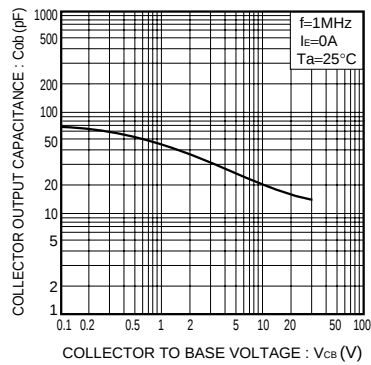


Fig.11 Collector output capacitance
vs. collector-base voltage

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